

# 74LVC1G32 Single 2-Input OR Gate

## **GENERAL DESCRIPTION**

The 74LVC1G32 provides a single 2-input OR gate that is designed for 1.65V to 5.5V V<sub>CC</sub> operation. The device performs the Boolean function Y = A + B or  $Y = \overline{\overline{A} \cdot \overline{B}}$  in positive logic.

Input can be driven from either 3.3V or 5V devices. The feature allows the use of the device in a mixed 3.3V and 5V environment.

Schmitt trigger action at all inputs makes the circuit tolerant for slower input rise and fall time.

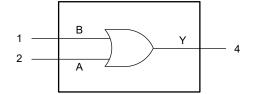
The CMOS device has high output drive while maintaining low static power dissipation over a broad  $V_{CC}$  operating range.

This device is fully specified for partial power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

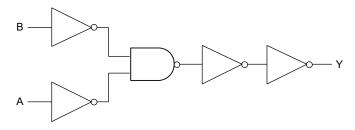
# FEATURES

- Wide Supply Voltage Range: 1.65V to 5.5V
- High Noise Immunity
- ±24mA Output Drive at V<sub>cc</sub> = 3.0V
- CMOS Low Power Consumption
- Direct Interface with TTL Levels
- Input Accepts Voltages up to 5V
- -40°C to +125°C Operating Temperature Range
- Available in a Green SC70-5 Package

### LOGIC SYMBOL



### LOGIC DIAGRAM



# FUNCTIONAL TABLE

INPUT		OUTPUT
А	В	Y
L	L	L
L	Н	Н
Н	L	Н
Н	Н	Н

 $Y = A + B \text{ or } Y = \overline{\overline{A} \cdot \overline{B}}$ H = High Voltage Level L = Low Voltage Level



### **PACKAGE/ORDERING INFORMATION**

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
74LVC1G32	SC70-5	-40°C to +125°C	74LVC1G32XC5G/TR	R57XX	Tape and Reel, 3000

#### MARKING INFORMATION

NOTE: XX = Date Code.

YYY X X Date Code - Week Date Code - Year Serial Number

Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

#### ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

Supply Voltage, V <sub>CC</sub>	
Input Voltage, V <sub>I</sub> <sup>(2)</sup>	0.5V to 6.5V
Output Voltage, V <sub>O</sub> <sup>(2)</sup>	
Active Mode	0.5V to V <sub>CC</sub> + 0.5V
Power-Down Mode, V <sub>CC</sub> = 0V	0.5V to 6.5V
Input Clamping Current, I <sub>IK</sub> (V <sub>I</sub> < 0V)	50mA
Output Clamping Current, $I_{OK}$ (V <sub>O</sub> > V <sub>CC</sub> or	V <sub>0</sub> < 0V)
	±50mA
Output Current, $I_0$ (V <sub>0</sub> = 0V to V <sub>CC</sub> )	
Supply Current, I <sub>CC</sub>	50mA
Ground Current, I <sub>GND</sub>	50mA
Junction Temperature <sup>(3)</sup>	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (Soldering, 10s)	+260°C
ESD Susceptibility	
НВМ	6000V
CDM	1000V

#### **RECOMMENDED OPERATING CONDITIONS**

Supply Voltage, V <sub>CC</sub>	1.65V to 5.5V
Input Voltage, V <sub>I</sub>	0V to 5.5V
Output Voltage, V <sub>O</sub>	
Active Mode	$0V$ to $V_{CC}$
Power-Down Mode, V <sub>CC</sub> = 0V	0V to 5.5V
Input Transition Rise and Fall Rate, $\Delta t/\Delta V$	
V <sub>CC</sub> = 1.65V to 2.7V	20ns/V (MAX)
V <sub>CC</sub> = 2.7V to 5.5V	10ns/V (MAX)
Operating Temperature Range	40°C to +125°C

#### **OVERSTRESS CAUTION**

1. Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

2. The input and output voltage ratings may be exceeded if the input and output clamp current ratings are observed.

3. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability.

#### **ESD SENSITIVITY CAUTION**

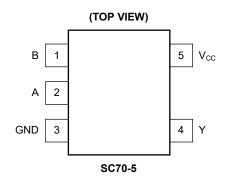
This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

#### DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.



# **PIN CONFIGURATION**



# **PIN DESCRIPTION**

PIN	NAME	FUNCTION
1, 2	B, A	Data Inputs.
3	GND	Ground.
4	Y	Data Output.
5	V <sub>CC</sub>	Supply Voltage.



# **ELECTRICAL CHARACTERISTICS**

(Full = -40°C to +125°C, all typical values are measured at  $V_{CC}$  = 3.3V and  $T_A$  = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL		CONDITIONS	TEMP	MIN	TYP	MAX	UNITS						
		V <sub>CC</sub> = 1.65V to	V <sub>CC</sub> = 1.65V to 1.95V		0.65 × V <sub>cc</sub>									
	N	V <sub>CC</sub> = 2.3V to 2.7V		Full	1.7			v						
High-Level Input Voltage	V <sub>IH</sub>	$V_{CC}$ = 2.7V to 3	3.6V	Full	2			v						
		$V_{CC}$ = 4.5V to §	5.5V	Full	$0.7 \times V_{CC}$									
		V <sub>CC</sub> = 1.65V to	1.95V	Full			0.35 × V <sub>CC</sub>							
1		$V_{CC}$ = 2.3V to 2	2.7V	Full			0.7							
Low-Level Input Voltage	VIL	$V_{CC}$ = 2.7V to 3	3.6V	Full			0.8	V						
		$V_{CC}$ = 4.5V to §	5.5V	Full			$0.3 \times V_{CC}$							
			$V_{CC}$ = 1.65V to 5.5V, $I_{\rm O}$ = -100 $\mu A$	Full	V <sub>CC</sub> - 0.05	V <sub>CC</sub> - 0.01								
			V <sub>CC</sub> = 1.65V, I <sub>O</sub> = -4mA	Full	1.43	1.55		V						
	N	$V_{I} = V_{IH}$ or $V_{IL}$	V <sub>CC</sub> = 2.3V, I <sub>O</sub> = -8mA	Full	2.02	2.18								
High-Level Output Voltage	V <sub>OH</sub>	$v_{I} = v_{IH} \text{ or } v_{IL}$	V <sub>CC</sub> = 2.7V, I <sub>O</sub> = -12mA	Full	2.38	2.56								
			V <sub>CC</sub> = 3.0V, I <sub>O</sub> = -24mA	Full	2.52	2.74								
			V <sub>CC</sub> = 4.5V, I <sub>O</sub> = -32mA	Full	4	4.22								
									$V_{CC}$ = 1.65V to 5.5V, $I_{O}$ = 100 $\mu$ A	Full		0.01	0.05	
			V <sub>CC</sub> = 1.65V, I <sub>O</sub> = 4mA	Full		0.1	0.22							
			$V_{I} = V_{IH} \text{ or } V_{IL}$	V <sub>CC</sub> = 2.3V, I <sub>O</sub> = 8mA	Full		0.12	0.28	v					
Low-Level Output Voltage	V <sub>OL</sub>	$v_{\rm I} = v_{\rm IH} \text{ or } v_{\rm IL}$	V <sub>CC</sub> = 2.7V, I <sub>O</sub> = 12mA	Full		0.16	0.34	v						
			V <sub>CC</sub> = 3.0V, I <sub>O</sub> = 24mA	Full		0.3	0.56							
			V <sub>CC</sub> = 4.5V, I <sub>O</sub> = 32mA	Full		0.32	0.6							
Input Leakage Current	l <sub>i</sub>	$V_{\rm CC}$ = 0V to 5.5	5V, V <sub>1</sub> = 5.5V or GND	Full		±0.01	±1	μA						
Power-Off Leakage Current	I <sub>OFF</sub>	$V_{CC} = 0V$ , $V_I$ or $V_O = 5.5V$		Full		±0.01	±1	μA						
Supply Current	Icc		$V_{\text{CC}}$ = 1.65V to 5.5V, $V_{\text{I}}$ = 5.5V or GND, $I_{\text{O}}$ = 0A			0.01	1	μA						
Additional Supply Current	ΔI <sub>CC</sub>	Per pin, $V_{CC}$ = $I_0$ = 0A	Per pin, $V_{CC}$ = 2.3V to 5.5V, $V_I$ = $V_{CC}$ - 0.6V, $I_O$ = 0A			0.05	10	μA						
Input Capacitance	Cı	$V_{CC}$ = 3.3V, $V_{I}$	= GND to V <sub>CC</sub>	+25°C		3.5		pF						

# **DYNAMIC CHARACTERISTICS**

(For test circuit, see Figure 1. All typical values are measured at  $T_A = +25^{\circ}C$  and  $V_{CC} = 1.8V$ , 2.5V, 2.7V, 3.3V and 5.0V respectively, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		TEMP	MIN	TYP	MAX	UNITS
Propagation Delay <sup>(1)</sup>	Inc	A, B to Y, see Figure 2	V <sub>CC</sub> = 1.65V to 1.95V	+25°C		7.2		
			V <sub>CC</sub> = 2.3V to 2.7V	+25°C		3.9		
			V <sub>CC</sub> = 2.7V	+25°C		3.5		ns
			V <sub>CC</sub> = 3.0V to 3.6V	+25°C		3.2		
			V <sub>CC</sub> = 4.5V to 5.5V	+25°C		2.7		
Power Dissipation Capacitance <sup>(2)</sup>	C <sub>PD</sub>	V <sub>CC</sub> = 3.3V, V <sub>I</sub> :	= GND to V <sub>CC</sub>	+25°C		18		pF

#### NOTES:

- 1.  $t_{\text{PD}}$  is the same as  $t_{\text{PLH}}$  and  $t_{\text{PHL}}$ .
- 2.  $C_{\text{PD}}$  is used to determine the dynamic power dissipation (P\_D in  $\mu W).$

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \Sigma (C_{L} \times V_{CC}^{2} \times f_{o})$ where:

 $f_i$  = Input frequency in MHz.

 $f_o = Output$  frequency in MHz.

 $C_L$  = Output load capacitance in pF.

V<sub>CC</sub> = Supply voltage in Volts.

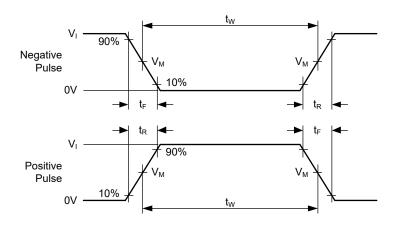
N = Number of inputs switching.

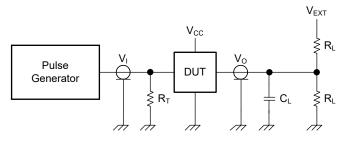
 $\Sigma(C_L \times V_{CC}^2 \times f_o) = Sum of outputs.$ 



## 74LVC1G32

# **TEST CIRCUIT**





Test conditions are given in Table 1.

Definitions for test circuit:

R<sub>L</sub> = Load resistance.

C<sub>L</sub> = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to the output impedance Zo of the pulse generator.

V<sub>EXT</sub> = External voltage for measuring switching times.

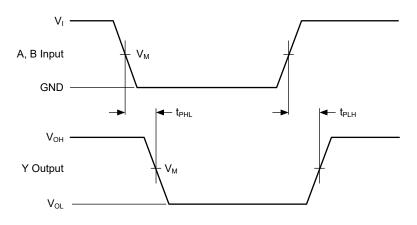
#### Figure 1. Test Circuit for Measuring Switching Times

#### Table 1. Test Conditions

SUPPLY VOLTAGE	INPUT		LOAD		V <sub>EXT</sub>
Vcc	Vı	t <sub>R</sub> = t <sub>F</sub>	CL	RL	t <sub>PLH</sub> , t <sub>PHL</sub>
1.65V to 1.95V	V <sub>CC</sub>	≤ 2.0ns	30pF	1kΩ	Open
2.3V to 2.7V	Vcc	≤ 2.0ns	30pF	500Ω	Open
2.7V	2.7V	≤ 2.5ns	50pF	500Ω	Open
3.0V to 3.6V	2.7V	≤ 2.5ns	50pF	500Ω	Open
4.5V to 5.5V	V <sub>CC</sub>	≤ 2.5ns	50pF	500Ω	Open

### 74LVC1G32

### WAVEFORMS



Test conditions are given in Table 1.

Measurement points are given in Table 2.

Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

#### Figure 2. The Data Input A, B to Output Y Propagation Delays

#### Table 2. Measurement Points

SUPPLY VOLTAGE	INPUT	OUTPUT
V <sub>cc</sub>	V <sub>M</sub>	V <sub>M</sub>
1.65V to 1.95V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
2.3V to 2.7V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
2.7V	1.5V	1.5V
3.0V to 3.6V	1.5V	1.5V
4.5V to 5.5V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$

#### **REVISION HISTORY**

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

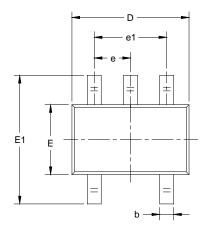
Changes from Original (FEBRUARY 2021) to REV.A	Page
Changed from product preview to production data	All

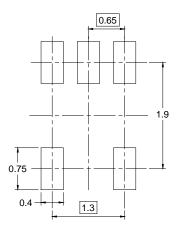
$\bigcirc$	SG Micro Corp
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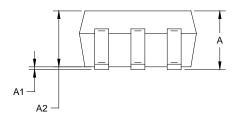
# PACKAGE OUTLINE DIMENSIONS

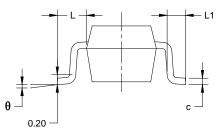
# SC70-5





RECOMMENDED LAND PATTERN (Unit: mm)

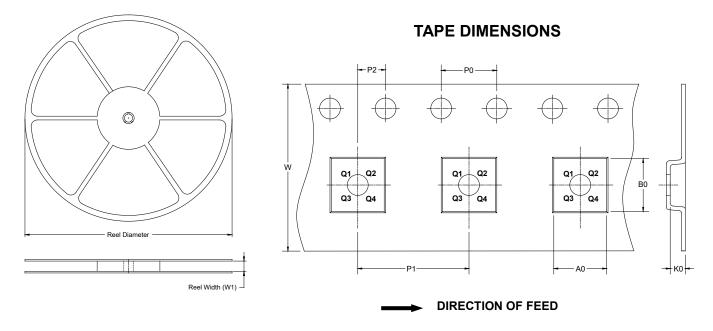




Symbol	-	Dimensions In Millimeters		nsions ches	
	MIN	MAX	MIN	MAX	
A	0.800	1.100	0.031	0.043	
A1	0.000	0.100	0.000	0.004	
A2	0.800	1.000	0.031	0.039	
b	0.150	0.350	0.006	0.014	
с	0.080	0.220	0.003	0.009	
D	2.000	2.200	0.079	0.087	
E	1.150	1.350	0.045	0.053	
E1	2.150	2.450	0.085	0.096	
е	0.65	TYP	0.026	6 TYP	
e1	1.300	) BSC	0.051 BSC		
L	0.525	5 REF	0.021 REF		
L1	0.260	0.460	0.010	0.018	
θ	0°	8°	0°	8°	

# TAPE AND REEL INFORMATION

#### **REEL DIMENSIONS**

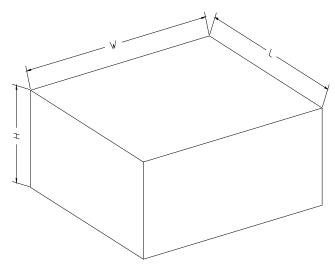


NOTE: The picture is only for reference. Please make the object as the standard.

#### KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SC70-5	7″	9.5	2.25	2.55	1.20	4.0	4.0	2.0	8.0	Q3

#### **CARTON BOX DIMENSIONS**



NOTE: The picture is only for reference. Please make the object as the standard.

#### **KEY PARAMETER LIST OF CARTON BOX**

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton	
7" (Option)	368	227	224	8	
7"	442	410	224	18	00002



单击下面可查看定价,库存,交付和生命周期等信息

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